



#### **DUAL SCHMITT TRIGGER INVERTERS**

#### **Description**

The Advanced Ultra Low Power (AUP) CMOS logic family is designed for low power and extended battery life in portable applications.

The 74AUP2G14 is composed of two Schmitt trigger inverters with standard push-pull outputs designed for operation over a power supply range of 0.8V to 3.6V. The device is fully specified for partial power down applications using I<sub>OFF</sub>. The I<sub>OFF</sub> circuitry disables the output preventing damaging current backflow when the device is powered down. The gates perform the positive Boolean function:

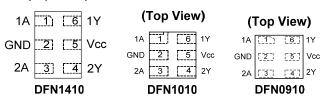
 $Y = \overline{A}$ 

#### **Features**

- Advanced Ultra Low Power (AUP) CMOS
- Supply Voltage Range from 0.8V to 3.6V
- ± 4mA Output Drive at 3.0V
- Low Static power consumption
- I<sub>CC</sub> < 0.9µA</li>
- Low Dynamic Power Consumption
- C<sub>PD</sub> = 4pF Typical at 3.6V
- Schmitt Trigger Action at All Inputs Make the Circuit Tolerant for Slower Input Rise and Fall Time.
- I<sub>OFF</sub> Supports Partial-Power-Down Mode Operation
- ESD Protection per JESD 22
  - Exceeds 200-V Machine Model (A115)
  - Exceeds 2000-V Human Body Model (A114)
  - Exceeds 1000-V Charged Device Model (C101)
- Latch-Up Exceeds 100mA per JESD 78, Class I
- Leadless packages per JESD30E
  - DFN1410 denoted as X2-DFN1410-6
  - DFN1010 denoted as X2-DFN1010-6
  - DFN0910 denoted as X2-DFN0910-6
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

### **Pin Assignments**

#### (Top View)



### **Applications**

- Suited for battery and low power needs
- Wide array of products such as:
  - PCs, networking, notebooks, netbooks, PDAs
  - Tablet Computers, E-readers
  - Computer peripherals, hard drives, CD/DVD ROM
  - TV, DVD, DVR, set top box
  - Cell Phones, Personal Navigation / GPS
  - MP3 players ,Cameras, Video Recorders

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

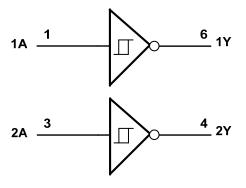
Click here for ordering information, located at the end of datasheet



# **Pin Descriptions**

Pin Name	Pin NO	Function
1A	1	Data Input
GND	2	Ground
2A	3	Data Input
2Y	4	Data Output
V <sub>CC</sub>	5	Supply Voltage
1Y	6	Data Output

# **Logic Diagram**



# **Function Table Diagram**

Inputs	Output
nA	nY
Н	L
L	Н



### Absolute Maximum Ratings (Note 4) (@TA = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit	
ESD HBM	Human Body Model ESD Protection	2	kV	
ESD CDM	Charged Device Model ESD Protection	1	kV	
ESD MM	Machine Model ESD Protection	200	V	
$V_{CC}$	Supply Voltage Range	-0.5 to +4.6	V	
VI	Input Voltage Range	-0.5 to +4.6	V	
Vo	Voltage Applied to Output in High or Low State	-0.5 to V <sub>CC</sub> +0.5		
lık	Input Clamp Current V <sub>I</sub> < 0	50	mA	
I <sub>OK</sub>	Output Clamp Current (V <sub>O</sub> < 0 )	-50	mA	
Io	Continuous Output Current (V <sub>O</sub> = 0 to V <sub>CC</sub> )	±20	mA	
Icc	Continuous Current Through V <sub>CC</sub>	50	mA	
I <sub>GND</sub>	Continuous Current Through GND	-50	mA	
TJ	Operating Junction Temperature	-40 to +150	°C	
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C	

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

### Recommended Operating Conditions (Note 5) (@TA = +25°C, unless otherwise specified.)

Symbol	Pa	arameter	Min	Max	Unit
Vcc	Operating Voltage		0.8	3.6	V
Vı	Input Voltage	·	0	3.6	V
Vo	Output Voltage		0	Vcc	V
		V <sub>CC</sub> = 0.8V		-20	μA
		V <sub>CC</sub> = 1.1V		-1.1	
	High-Level	V <sub>CC</sub> = 1.4		-1.7	1
I <sub>OH</sub>	Output Current	V <sub>CC</sub> = 1.65V		-1.9	mA
		V <sub>CC</sub> = 2.3V		-3.1	
		V <sub>CC</sub> = 3.0		-4	
		V <sub>CC</sub> = 0.8		20	μΑ
		V <sub>CC</sub> = 1.1V		1.1	
	Low-Level	V <sub>CC</sub> = 1.4V		1.7	
I <sub>OL</sub>	Output Current	V <sub>CC</sub> = 1.65V		1.9	mA
		V <sub>CC</sub> = 2.3V		3.1	1
		V <sub>CC</sub> = 3.0V		4	1
TA	Operating Free-Air Temperature		-40	+125	°C

Note: 5. Unused inputs should be held at  $V_{\text{CC}}$  or Ground.



# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Cumbal	Darameter	Toot Conditions	V	T <sub>A</sub> = -	+25°C	T <sub>A</sub> = -40°0	c to +85°C	Unit	
Symbol	Parameter	Test Conditions	V <sub>CC</sub>	Min	Max	Min	Max		
			0.8V	0.3	0.6	0.3	0.6		
			1.1V	0.53	0.9	0.53	0.9		
$V_{T+}$	Positive-going Input Threshold		1.4V	0.74	1.11	0.74	1.11	V	
V   +	Voltage		1.65V	0.91	1.29	0.91	1.29	V	
			2.3V	1.37	1.77	1.37	1.77		
			3.0V	1.88	2.29	1.88	2.29		
			V8.0	0.1	0.6	0.1	0.6		
	Negative-going Input Threshold		1.1V	0.26	0.65	0.26	0.65		
$V_{T-}$	Voltage		1.4V	0.39	0.75	0.39	0.75	V	
			1.65V	0.47	0.84	0.47	0.84		
			2.3V	0.69	1.04	0.69	1.04		
			3.0V	0.88	1.24	0.88	1.24		
			0.8V	0.07	0.5	0.07	0.5		
	I hardana a'a		1.1V	0.08	0.46	0.08	0.46		
$\Delta V_{T}$	Hysteresis (V <sub>T+</sub> - V <sub>T-)</sub>		1.4V	0.18	0.56	0.18	0.56	V	
	(VI+- VI-)		1.65V 2.3V	0.27 0.53	0.66 0.92	0.27 0.53	0.66 0.92		
			3.0V	0.79	1.31	0.33	1.31		
		I <sub>OH</sub> = -20μA	0.8V to 3.6V	V <sub>CC</sub> – 0.1	1.01	V <sub>CC</sub> – 0.1	1.01		
		I <sub>OH</sub> = -1.1mA	1.1V	0.75 X V <sub>CC</sub>		0.7 X V <sub>CC</sub>			
		I <sub>OH</sub> = -1.7mA	1.4V	1.11		1.03			
			1.65V	1.32		1.30			
$V_{OH}$	High-Level Output Voltage	I <sub>OH</sub> = -1.9mA	1.05V	2.05		1.97		V	
		I <sub>OH</sub> = -2.3mA				1.85			
		I <sub>OH</sub> = -3.1mA		1.9					
		I <sub>OH</sub> = -2.7mA	3V	2.72		2.67			
		I <sub>OH</sub> = -4mA		2.6		2.55			
		I <sub>OL</sub> = 20μA	0.8V to 3.6V		0.1		0.1		
		I <sub>OL</sub> = 1.1mA	1.1V		0.3 X V <sub>CC</sub>		0.3 X V <sub>CC</sub>		
		I <sub>OL</sub> = 1.7mA	1.4V		0.31		0.37		
$V_{OL}$	Low-Level Output Voltage	I <sub>OL</sub> = 1.9mA	1.65V		0.31		0.35	V	
VOL	Low Love, output vertage	I <sub>OL</sub> = 2.3 mA	2.3V		0.31		0.33	•	
		$I_{OL}$ = 3.1mA	2.0 V		0.44		0.45		
		I <sub>OL</sub> = 2.7mA	3V		0.31		0.33		
		I <sub>OL</sub> = 4mA	30		0.44		0.45		
II	Input Current	V <sub>I</sub> = GND to 3.6V	0 to 3.6V		± 0.1		± 0.5	μA	
I <sub>OFF</sub>	Power Down Leakage Current	$V_1$ or $V_0$ = 0V to 3.6V	0		± 0.2		± 0.5	μA	
Δl <sub>OFF</sub>	Delta Power Down Leakage Current	$V_I$ or $V_O = 0V$ to 3.6V	0V to 0.2V		± 0.2		± 0.6	μA	
I <sub>CC</sub>	Supply Current	V <sub>I</sub> = GND or V <sub>CC</sub> , I <sub>O</sub> = 0	0.8V to 3.6V		0.5		0.9	μA	



### Electrical Characteristics (cont.) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions	Vaa	T <sub>A</sub> = -40°C	to +125°C	Unit	
Symbol	Parameter	rest Conditions	V <sub>CC</sub>	Min	Max		
			0.8V	0.3	0.62		
			1.1V	0.53	0.92		
\/_	Positive-going Input Threshold		1.4V	0.74	1.13	V	
$V_{T+}$	Voltage		1.65V	0.91	1.31	V	
			2.3V	1.37	1.80		
			3.0V	1.88	2.32		
			V8.0	0.1	0.6		
	Negative going Input Threshold		1.1V	0.26	0.65		
$V_{T-}$	Negative-going Input Threshold Voltage		1.4V	0.39	0.75	V	
			1.65V	0.47	0.84	·	
			2.3V	0.69	1.04		
			3.0V	0.88	1.24		
			V8.0	0.07	0.5		
			1.1V	0.08	0.46		
$\Delta V_T$	Hysteresis		1.4V	0.18	0.56	V	
Δν	T (V <sub>T+</sub> - V <sub>T-)</sub>		1.65V	0.27	0.66	v	
			2.3V	0.53	0.92		
			3.0V	0.79	1.31		
		I <sub>OH</sub> = -20μA	0.8V to 3.6V	V <sub>CC</sub> – 0.11			
		I <sub>OH</sub> = -1.1mA	1.1V	0.6 X V <sub>CC</sub>			
		I <sub>OH</sub> = -1.7mA	1.4V	0.93			
.,	High Lavel Output Valtage	I <sub>OH</sub> = -1.9mA	1.65V	1.17		V	
V <sub>OH</sub>	High-Level Output Voltage	I <sub>OH</sub> = -2.3mA	0.01/	1.77		V	
		I <sub>OH</sub> = -3.1mA	2.3V	1.67			
		I <sub>OH</sub> = -2.7mA		2.40			
		I <sub>OH</sub> = -4mA	- 3V	2.30			
		I <sub>OL</sub> = 20μA	0.8V to 3.6V		0.11		
		I <sub>OL</sub> = 1.1mA	1.1V		0.33 X V <sub>CC</sub>		
		I <sub>OL</sub> = 1.7mA	1.4V		0.41		
		I <sub>OL</sub> = 1.9mA	1.65V		0.39		
$V_{OL}$	Low-Level Output Voltage	I <sub>OL</sub> = 2.3mA			0.36	V	
		I <sub>OL</sub> = 3.1mA	2.3V		0.50		
		I <sub>OL</sub> = 2.7mA			0.36		
		I <sub>OL</sub> = 4mA	- 3V		0.50		
l <sub>l</sub>	Input Current	V <sub>I</sub> = GND to 3.6V	0 to 3.6V	+	± 0.75	μA	
	Power Down Leakage Current	$V_1$ or $V_0 = 0V$ to 3.6V	0 to 3:0V		± 0.75	μA	
I <sub>OFF</sub>	_			+			
Δl <sub>OFF</sub>	Delta Power Down Leakage Current	$V_1$ or $V_0 = 0V$ to 3.6V	0V to 0.2V		± 2.5	μA	
Icc	Supply Current	$V_1 = GND \text{ or } V_{CC}, I_0 = 0$	0.8V to 3.6V		1.4	μA	
$\Delta I_{CC}$	Additional Supply Current	Input at V <sub>CC</sub> -0.6V	3.3V		75	μΑ	



# **Switching Characteristics**

C<sub>L</sub>=5pF see Figure 1

Parameter	From	_	V	T <sub>A</sub> = +25°C		T <sub>A</sub> = -40°C to +85°C		T <sub>A</sub> = -40°C to +125°C		Unit	
Inpu	Input		Vcc	Min	Тур	Max	Min	Max	Min	Max	Ollit
			V8.0		19.9						
		Y	1.2V ± 0.1V	2.7	5.9	11.0	2.4	11.1	2.4	11.2	ns
	۸		1.5V ± 0.1V	2.6	4.3	6.6	2.4	7.1	2.4	7.4	
t <sub>pd</sub>	Α		1.8V ± 0.15V	2.1	3.7	5.4	2.0	6.0	2.0	6.2	
			2.5V ± 0.2V	1.2	2.4	3.9	1.1	4.5	1.1	5.0	
			3.3V ± 0.3V	1.1	2.1	3.2	1.0	3.9	1.0	4.3	

C<sub>I</sub> =10pF see Figure 1

Parameter From Input	From	то	V		T <sub>A</sub> = +25°0	;	T <sub>A</sub> = -40°C to +85°C		T <sub>A</sub> = -40°C to +125°C		Unit
	OUTPUT	Vcc	Min	Тур	Max	Min	Max	Min	Max	UIIIL	
			V8.0		23.4						
		Y	1.2V ± 0.1V	2.9	6.8	12.7	2.8	12.8	2.8	12.9	- ns
	۸		1.5V ± 0.1V	2.8	5.0	7.7	2.6	8.2	2.6	8.6	
t <sub>pd</sub>	Α		1.8V ± 0.15V	2.7	4.2	6.2	2.5	6.7	2.5	7.1	
			2.5V ± 0.2V	1.6	2.9	4.6	1.5	5.4	1.5	6.0	
			3.3V ± 0.3V	1.5	2.7	3.8	1.4	4.5	1.4	5.0	

C<sub>I</sub> =15pF see Figure 1

Parameter From		то	V <sub>CC</sub>		T <sub>A</sub> = +25°C	;	T <sub>A</sub> = -40°C to +85°C		T <sub>A</sub> = -40°C to +125°C		Unit
Input OUTPUT	OUTPUT	<b>V</b> CC	Min	Тур	Max	Min	Max	Min	Max	Oill	
			V8.0		26.9						
		Y	1.2V ± 0.1V	3.3	7.6	14.3	3.0	17.3	3.0	18.5	ns
	^		1.5V ± 0.1V	3.3	5.5	8.6	2.9	9.4	2.9	9.8	
t <sub>pd</sub>	Α		1.8V ± 0.15V	2.8	4.7	7.0	2.8	7.7	2.8	8.1	
			2.5V ± 0.2V	2.1	3.3	5.1	1.8	6.1	1.8	6.8	
			3.3V ± 0.3V	2.0	3.1	4.2	1.8	5.0	1.8	5.5	

C<sub>L</sub>=30pF see Figure 1

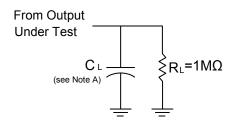
Parameter	From	то	V		T <sub>A</sub> = +25°C	;	T <sub>A</sub> = -40°C to +85°C		T <sub>A</sub> = -40°C to +125°C		Unit
Input	OUTPUT	V <sub>CC</sub>	Min	Тур	Max	Min	Max	Min	Max	Onit	
			V8.0		37.3						
		Y	1.2V ± 0.1V	4.0	9.8	18.7	3.9	19.6	3.9	20.0	ns
			1.5V ± 0.1V	3.7	7.1	11.2	3.8	12.3	3.8	12.9	
t <sub>pd</sub>	Α		1.8V ± 0.15V	3.6	6.0	9.1	3.5	10.0	3.5	10.6	
			2.5V ± 0.2V	2.4	4.5	6.5	2.3	7.6	2.3	8.4	
			3.3V ± 0.3V	2.2	4.2	5.4	2.1	6.2	2.1	6.9	



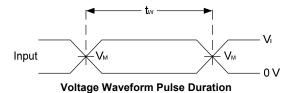
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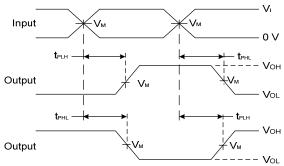
	Parameter	Test Conditions	Vcc	Тур	Unit
			0.8V	5.1	
	Power Dissipation	f = 1MHz No Load	1.2V ± 0.1V	5.2	
0			1.5V ± 0.1V	5.2	"r
$C_{pd}$	Capacitance		1.8V ± 0.15V	5.5	pF
			2.5V ± 0.2V	5.7	
			3.3V ± 0.3V	6.0	
Cı	Input Capacitance	V <sub>i</sub> = V <sub>CC</sub> or GND	0V or 3.3V	2.0	pF
Co	Output Capacitance	V <sub>O</sub> = V <sub>CC</sub> or GND	0V	2.0	pF

### **Parameter Measurement Information**



Vcc	In	puts	.,	
VCC	VI	t <sub>r</sub> /t <sub>f</sub>	V <sub>M</sub>	CL
0.8V	V <sub>CC</sub>	≤3ns	V <sub>CC</sub> /2	5, 10, 15, 30pF
1.2V ± 0.1V	Vcc	≤3ns	V <sub>CC</sub> /2	5, 10, 15, 30pF
1.5V ± 0.1V	V <sub>CC</sub>	≤3ns	V <sub>CC</sub> /2	5, 10, 15, 30pF
1.8V ± 0.15V	V <sub>CC</sub>	≤3ns	V <sub>CC</sub> /2	5, 10, 15, 30pF
2.5V ± 0.2V	V <sub>CC</sub>	≤3ns	V <sub>CC</sub> /2	5, 10, 15, 30pF
3.3V ± 0.3V	V <sub>CC</sub>	≤3ns	V <sub>CC</sub> /2	5, 10, 15, 30pF





Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

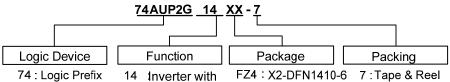
Figure 1. Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 10MHz.
- C. Inputs are measured separately one transition per measurement.
- D.  $t_{\text{PLH}}$  and  $t_{\text{PHL}}$  are the same as  $t_{\text{PD.}}$



### **Ordering Information**



AUP: 0.8 V to 3.6 V

Logic Family 2G: Dual Gate

Schmitt Trigger Input

FW4: X2-DFN1010-6

FW3: X2-DFN0910-6

Device	Paakaga Cada	Pookoging	7" Tape and I	Reel (Note 6)
Device	Package Code	Packaging	Quantity	Part Number Suffix
74AUP2G14FZ4-7	FZ4	X2-DFN1410-6	5000/Tape & Reel	-7
74AUP2G14FW4-7	FW4	X2-DFN1010-6	5000/Tape & Reel	-7
74AUP2G14FW3-7	FW3	X2-DFN0910-6	5000/Tape & Reel	-7

6. The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf Note:

### **Marking Information**

(1) X2-DFN1410-6, X2-DFN1010-6, X2-DFN0910-6

(Top View)

XX  $\frac{XX}{Y}$ : Identification Code  $\frac{X}{Y}$ : Year: 0~9

₩: Week: A~Z: 1~26 week; a~z: 27~52 week; z represents

52 and 53 week X: A~Z: Internal code

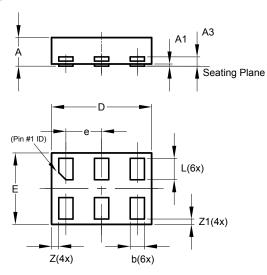
Part Number	Package	Identification Code
74AUP2G14FZ4	X2-DFN1410-6	RR
74AUP2G14FW4	X2-DFN1010-6	SR
74AUP2G14FW3	X2-DFN0910-6	MR



# Package Outline Dimensions (All dimensions in mm.)

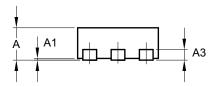
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

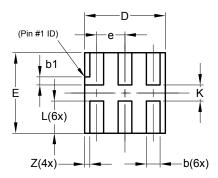
#### (1) Package Type X2-DFN1410-6



X2-DFN1410-6			
Dim	Min	Max	Тур
Α	_	0.40	0.39
A1	0.00	0.05	0.02
А3	_	_	0.13
b	0.15	0.25	0.20
D	1.35	1.45	1.40
Е	0.95	1.05	1.00
е			0.50
L	0.25	0.35	0.30
Z			0.10
<b>Z</b> 1	0.045	0.105	0.075
All Dimensions in mm			

#### (2) Package Type: X2-DFN1010-6





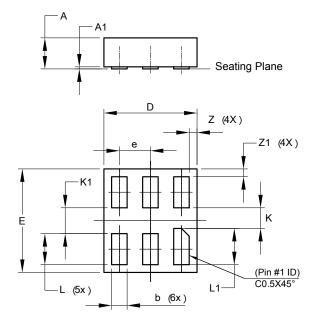
X2-DFN1010-6			
Dim	Min	Max	Тур
Α	_	0.40	0.39
A1	0.00	0.05	0.02
A3	_		0.13
b	0.14	0.20	0.17
b1	0.05	0.15	0.10
D	0.95	1.05	1.00
Е	0.95	1.05	1.00
е	_		0.35
١	0.35	0.45	0.40
K	0.15		
Z			0.065
All Dimensions in mm			



# Package Outline Dimensions (cont.) (All dimensions in mm.)

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

#### (3) Package Type: X2-DFN0910-6



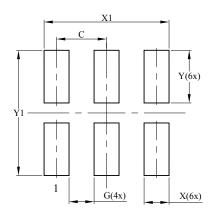
2	X2-DFN0910-6			
Dim	Min	Max	Тур	
Α	1	0.35	0.30	
A1	0	0.03	0.02	
b	0.10	0.20	0.15	
D	0.85	0.95	0.90	
Е	0.95	1.05	1.00	
е	1	-	0.30	
K	0.20	-	-	
K1	0.25	-	-	
L	0.25	0.35	0.30	
L1	0.30	0.40	0.35	
Z	-	-	0.075	
<b>Z</b> 1	-	-	0.075	
All D	All Dimensions in mm			



### **Suggested Pad Layout**

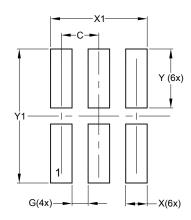
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

#### (1) Package Type X2-DFN1410-6



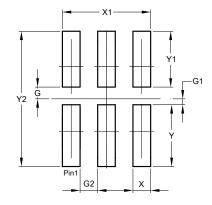
Dimensions	Value (in mm)
С	0.500
G	0.250
Х	0.250
X1	1.250
Y	0.525
Y1	1.250

### (2) Package Type: X2-DFN1010-6



Dimensions	Value (in mm)
С	0.350
G	0.150
Х	0.200
X1	0.900
Y	0.550
Y1	1 250

### (3) Package Type: X2-DFN0910-6



Dimensions	Value (in mm)
G	0.100
G1	0.050
G2	0.150
X	0.150
X1	0.750
Y	0.525
Y1	0.475
Y2	1.150



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